

6.0-18.0 GHz Broad Band Amplifier

General Description

The NB00446 is a broadband medium power amplifier with an operating frequency range of 6 to 18 GHz. The model is available in a miniature housing with replaceable SMA connectors. A thin film hybrid MIC process ensures robust characteristics over operating temperature range of -30 to +70 °C. The amplifier incorporates internally protected voltage regulators and can be biased in a wide range of DC voltage. The small size, high gain and output power make the amplifier ideal for any general-purpose applications.

Performance at 25 °C

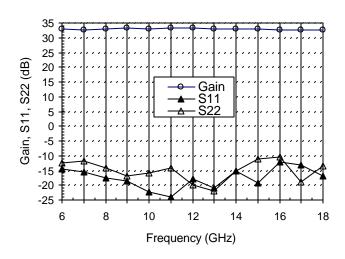
Parameter	Min.	Тур.	Max.	Units
Frequency	6.0		18.0	GHz
Gain	30	33		dB
Gain Flatness over Operating Frequency Range		± 1.2	± 2	dB
Noise Figure		5.5	7.0	dB
Output Power at 1 dB Compression	21	23		dBm
Input VSWR		1.7:1	2.0:1	
Output VSWR		1.9:1	2.0:1	
DC Supply Voltage (Vcc+)	+11	+12	+16	V
Supplied Current at +12 V (nominal bias, -17 dBm Pin)		420	480	mA



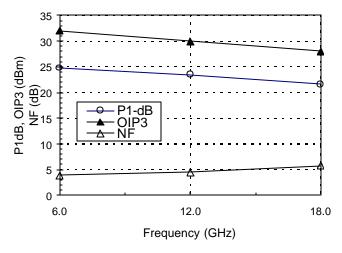
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Typical Test Data

Gain and Return Loss at 25 °C



Output P $_{\text{-1 dB}}, \text{IP}_{\text{3}}$ and Noise Figure at 25 $^{\text{0}}\text{C}$

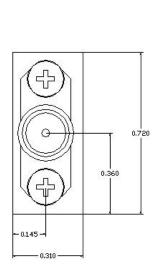


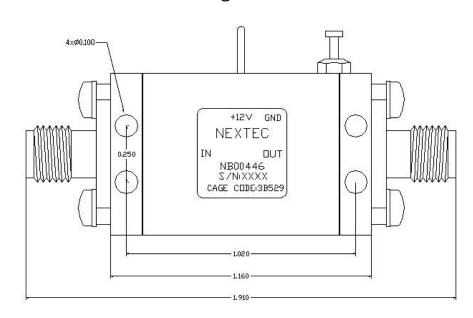
Customized Designs: For custom designs, including both electrical and mechanical, please contact us at sales@nextec-rf.com.



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Outline Drawing





(unit: inch)

Biasing and Operation

- 1. Turn off RF input power. The amplifier, being an active device, generates heat when bias is applied. Adequate heat sinking is required. Operating baseplate temperature should not exceed +70 °C.
- 2. Connect ground terminal.
- 3. Apply positive supply voltage of +12 V.
- 4. Turn on RF power. The input RF power should not exceed 0 dBm.

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